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SN74LV541A

SCLS410J-APRIL 1998-REVISED DECEMBER 2014

SN74LV541A Octal Buffers/Drivers With 3-State Outputs

1 Features

- 2-V to 5.5-V V_{CC} Operation
- Max t_{pd} of 6 ns at 5 V
- Typical V_{OLP} (Output Ground Bounce)
 < 0.8 V at V_{CC} = 3.3 V, T_A = 25°C
- Typical V_{OHV} (Output V_{OH} Undershoot) > 2.3 V at V_{CC} = 3.3 V, T_A = 25° C
- Support Mixed-Mode Voltage Operation on All Ports
- Ioff Supports Partial-Power-Down Mode Operation
- Latch-Up Performance Exceeds 250 mA Per JESD 17
- ESD Protection Exceeds JESD 22
 - 3000-V Human-Body Model
 - 200-V Machine Model
 - 2000-V Charged-Device Model

2 Applications

- Smart Grids
- TVs
- Set-Top-Boxes
- Audio
- Servers
- Surveillance Cameras
- Network Switches
- Infotainment

3 Description

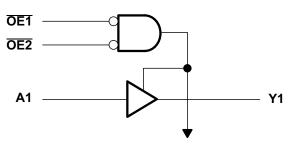
The SN74LV541A device is an octal buffer/driver designed for 2-V to 5.5-V V_{CC} operation.

Table 1. Device Information⁽¹⁾

PART NUMBER	PACKAGE	BODY SIZE (NOM)
	VQFN (20)	4.50 x 3.50 mm
	SSOP (20)	7.50 x 5.30 mm
SN74LV541A	TSSOP (20)	6.50 x 4.40 mm
	TVSOP (20)	5.00 x 4.40 mm
	SOIC (20)	12.80 x 7.50 mm

(1) For all available packages, see the orderable addendum at the end of the data sheet.

4 Simplified Schematic



To Seven Other Channels

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5 Revision History

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Changes from Revision I (April 2005) to Revision J

Added Applications, Device Information table, Pin Functions table, ESD Ratings table, Thermal Information table, Typical Characteristics, Feature Description section, Device Functional Modes, Application and Implementation section, Power Supply Recommendations section, Layout section, Device and Documentation Support section, and	
Mechanical, Packaging, and Orderable Information section.	. 1
Deleted Ordering Information table.	. 1
Changed MAX operating temperature to 125°C in Recommended Operating Conditions table.	. 5

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EXAS STRUMENTS

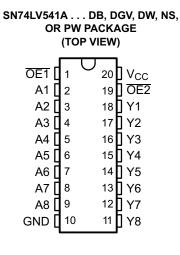
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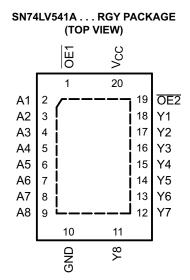


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6 Pin Configuration and Functions





Pin Functions

	PIN	TYPE	DESCRIPTION
NO.	NAME	TIPE	DESCRIPTION
1	OE1	I	Output Enable 1
2	A1	I	A1 Input
3	A2	I	A2 Input
4	A3	I	A3 Input
5	4A	I	A4 Input
6	A5	Ι	A5 Input
7	A6	I	A6 Input
8	A7	Ι	A7 Input
9	A8	I	A8 Input
10	GND	—	Ground Pin
11	Y8	0	Y8 Output
12	Y7	0	Y7 Output
13	Y6	0	Y6 Output
14	Y5	0	Y5 Output
15	Y4	0	Y4 Output
16	Y3	0	Y3 Output
17	Y2	0	Y2 Output
18	Y1	0	Y1 Output
19	OE2	I	Output Enable 2
20	V _{CC}	_	Power Pin

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7 Specifications

7.1 Absolute Maximum Ratings

over operating free-air temperature range (unless otherwise noted)⁽¹⁾

			MIN	MAX	UNIT
V_{CC}	Supply voltage range		-0.5	7	V
VI	Input voltage range ⁽²⁾		-0.5	7	V
Vo	Voltage range applied to any output in the high-impedance	-0.5	7	V	
Vo	Output voltage range applied in the high or low state $^{(2)(3)}$	-0.5	$V_{CC} + 0.5$	V	
I _{IK}	Input clamp current	V _I < 0		-20	mA
I _{OK}	Output clamp current	V _O < 0		-50	mA
I _O	Continuous output current	$V_{O} = 0$ to V_{CC}		±35	mA
	Continuous current through V _{CC} or GND			±70	mA
T _{stg}	Storage temperature range		-65	150	°C

(1) Stresses beyond those listed under Absolute Maximum Ratings may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under Recommended Operating Conditions is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

(3) This value is limited to 5.5-V maximum.

7.2 ESD Ratings

				VALUE	UNIT
			Human body model (HBM), per ANSI/ESDA/JEDEC JS-001, all pins ⁽¹⁾	3000	
V(ESD)	Electrostatic discharge	Charged device model (CDM), per JEDEC specification JESD22-C101, all $\ensuremath{pins^{(2)}}$	2000	V

(1) JEDEC document JEP155 states that 500-V HBM allows safe manufacturing with a standard ESD control process.

(2) JEDEC document JEP157 states that 250-V CDM allows safe manufacturing with a standard ESD control process.

⁽²⁾ The input and output negative-voltage ratings may be exceeded if the input and output current ratings are observed.



7.3 Recommended Operating Conditions

over operating free-air temperature range (unless otherwise noted)⁽¹⁾

			SN74LV54	1A	
			MIN	MAX	UNIT
V _{CC}	Supply voltage		2	5.5	V
		$V_{CC} = 2 V$	1.5		
V		V_{CC} = 2.3 V to 2.7 V	V _{CC} × 0.7		V
V _{IH}	High-level input voltage	V _{CC} = 3 V to 3.6 V	V _{CC} × 0.7		v
		V_{CC} = 4.5 V to 5.5 V	V _{CC} × 0.7		
		$V_{CC} = 2 V$		0.5	
V	Low-level input voltage	V_{CC} = 2.3 V to 2.7 V		$V_{CC} \times 0.3$	V
V _{IL}	Low-level input voltage	V_{CC} = 3 V to 3.6 V		$V_{CC} \times 0.3$	v
		V_{CC} = 4.5 V to 5.5 V		$V_{CC} \times 0.3$	
VI	Input voltage		0	5.5	V
V	Output voltage	High or low state	0	V _{CC}	V
Vo	Oulput voltage	3-state	0	5.5	v
		$V_{CC} = 2 V$		-50	μA
L	High-level output current	V_{CC} = 2.3 V to 2.7 V		-2	
I _{OH}	High-level output current	V_{CC} = 3 V to 3.6 V		-8	mA
		V_{CC} = 4.5 V to 5.5 V		-16	
		$V_{CC} = 2 V$		50	μA
	Low-level output current	V_{CC} = 2.3 V to 2.7 V		2	
I _{OL}	Low-level output current	V_{CC} = 3 V to 3.6 V		8	mA
		V_{CC} = 4.5 V to 5.5 V		16	
		V_{CC} = 2.3 V to 2.7 V		200	
∆t/∆v	Input transition rise or fall rate	V_{CC} = 3 V to 3.6 V		100	ns/V
		V_{CC} = 4.5 V to 5.5 V		20	
T _A	Operating free-air temperature		-40	125	°C

(1) All unused inputs of the device must be held at V_{CC} or GND to ensure proper device operation. Refer to the TI application report, *Implications of Slow or Floating CMOS Inputs* (SCBA004).

7.4 Thermal Information

				SN74L	V541A			
	THERMAL METRIC ⁽¹⁾	DB	DGV	DW	NS	PW	RGY	UNIT
		20 PINS						
$R_{\theta JA}$	Junction-to-ambient thermal resistance	96.0	116.1	79.8	77.1	102.8	35.1	
R _{0JC(top)}	Junction-to-case (top) thermal resistance	57.7	31.3	45.8	43.6	36.8	43.3	
$R_{\theta JB}$	Junction-to-board thermal resistance	51.2	57.6	47.4	44.6	53.8	12.9	
Ψյτ	Junction-to-top characterization parameter	19.4	1.0	18.5	17.2	2.5	0.9	°C/W
Ψ _{JB}	Junction-to-board characterization parameter	50.8	56.9	47.0	44.2	53.3	12.9	
R _{0JC(bot)}	Junction-to-case (bottom) thermal resistance	_	_	_	_	_	7.9	

(1) For more information about traditional and new thermal metrics, see the IC Package Thermal Metrics application report (SPRA953).

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7.5 Electrical Characteristics

	TEST CONDITIONS	V	Τ,	λ = 25°C		–40°C to	85°C	–40°C to 125°C		UNIT
PARAMETER	TEST CONDITIONS	V _{cc}	MIN	TYP	MAX	MIN	MAX	MIN	MAX	UNIT
	I _{OH} = -50 μA	2 V to 5.5 V	V _{CC} – 0.1			V _{CC} – 0.1		V _{CC} – 0.1		
V _{OH}	$I_{OH} = -2 \text{ mA}$	2.3 V	2			2		2		V
	I _{OH} = -8 mA	3 V	2.48			2.48		2.48		
	I _{OH} = -16 mA	4.5 V	3.8			3.8		3.8		
	I _{OL} = 50 μA	2 V to 5.5 V			0.1		0.1		0.1	
V _{OL}	$I_{OL} = 2 \text{ mA}$	2.3 V			0.4		0.4		0.4	V
	$I_{OL} = 8 \text{ mA}$	3 V			0.44		0.44		0.44	
	I _{OL} = 16 mA	4.5 V			0.55		0.55		0.55	
I _I	$V_1 = 5.5 V \text{ or GND}$	0 to 5.5 V			±1		±1		±1	μA
I _{OZ}	$V_{O} = V_{CC}$ or GND	5.5 V			±5		±5		±5	μA
I _{CC}	$V_I = V_{CC} \text{ or } GND, \qquad I_O = 0$	5.5 V			20		20		20	μA
l _{off}	$V_1 \text{ or } V_0 = 0 \text{ to } 5.5 \text{ V}$				5		5		5	μA
Ci	$V_I = V_{CC}$ or GND	3.3 V		2						pF

over recommended operating free-air temperature range (unless otherwise noted)

7.6 Switching Characteristics, V_{cc} = 2.5 V ± 0.2 V

over recommended operating free-air temperature range (unless otherwise noted) (see Figure 3)

PARAMETER	FROM TO		LOAD	T _A = 25°C			–40°C to 85°C		–40°C to 125°C		UNIT	
FARAMETER	(INPUT)	(INPUT) (OUTPUT)	(OUTPUT)	CAPACITANCE	MIN	TYP	MAX	MIN	MAX	MIN	MAX	UNIT
t _{pd}	А	Y			6.7 ⁽¹⁾	11.3 ⁽¹⁾	1	13.5	1	13.5		
t _{en}	OE	Y	C _L = 15 pF		8.5 ⁽¹⁾	16.6 ⁽¹⁾	1	19.5	1	19.5	ns	
t _{dis}	OE	Y			8.4 ⁽¹⁾	13.1 ⁽¹⁾	1	15	1	15		
t _{pd}	А	Y			8.7	15.9	1	18.5	1	18.5		
t _{en}	OE	Y	0 50 55		10.5	20.7	1	24	1	24		
t _{dis}	OE	Y	C _L = 50 pF		12.3	17.9	1	20	1	20	ns	
t _{sk(o)}						2		2		2		

(1) On products compliant to MIL-PRF-38535, this parameter is not production tested.

7.7 Switching Characteristics, $V_{CC} = 3.3 V \pm 0.3 V$

over recommended operating free-air temperature range (unless otherwise noted) (see Figure 3)

DADAMETED	FROM	то	LOAD CAPACITANCE	T _A = 25°C	T _A = 25°C		–40°C to 85°C		125°C	
PARAMETER	(INPUT)) (OUTPUT)		MIN TYP	MAX	MIN	MAX	MIN	MAX	UNIT
t _{pd}	А	Y		4.8 ⁽¹⁾	7 ⁽¹⁾	1	8.5	1	8.5	
t _{en}	OE	Y	C _L = 15 pF	6.1 ⁽¹⁾	10.5 ⁽¹⁾	1	12.5	1	12.5	ns
t _{dis}	ŌE	Y		5.8 ⁽¹⁾	11 ⁽¹⁾	1	12	1	12	
t _{pd}	А	Y		6.1	10.5	1	12	1	12	
t _{en}	OE	Y		7.4	14	1	16	1	16	
t _{dis}	OE	Y	C _L = 50 pF	8.8	15.4	1	17.5	1	17.5	ns
t _{sk(o)}					1.5		1.5		1.5	

(1) On products compliant to MIL-PRF-38535, this parameter is not production tested.



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7.8 Switching Characteristics, $V_{cc} = 5 V \pm 0.5 V$

over recommended operating free-air temperature range (unless otherwise noted) (see Figure 3)

	•	Ŭ				, ,	• ·	1000 10	40500		
PARAMETER	FROM (INPUT)	FROM	то	LOAD	T _A = 25°	L	–40°C to	85.0	–40°C to	125 0	UNIT
		(OUTPUT)	CAPACITANCE	MIN TYP	MAX	MIN	MAX	MIN	MAX	ONIT	
t _{pd}	А	Y		3.5 ⁽¹⁾	5 ⁽¹⁾	1	6	1	6		
t _{en}	OE	Y	C _L = 15 pF	4.3 ⁽¹⁾	7.2 ⁽¹⁾	1	8.5	1	8.5	ns	
t _{dis}	OE	Y		3.9 ⁽¹⁾	7.5 ⁽¹⁾	1	8	1	8		
t _{pd}	А	Y		4.3	7	1	8	1	8		
t _{en}	OE	Y	0 50 - 5	5.3	9.2	1	10.5	1	10.5		
t _{dis}	OE	Y	C _L = 50 pF	5.6	8.8	1	10	1	10	ns	
t _{sk(o)}					1		1		1		

(1) On products compliant to MIL-PRF-38535, this parameter is not production tested.

7.9 Noise Characteristics⁽¹⁾

 V_{CC} = 3.3 V, C_L = 50 pF, T_A = 25°C

	PARAMETER	SN			
	PARAMETER	MIN	TYP	MAX	UNIT
V _{OL(P)}	Quiet output, maximum dynamic V _{OL}		0.5	0.8	V
V _{OL(V)}	Quiet output, minimum dynamic V _{OL}		-0.4	-0.8	V
V _{OH(V)}	Quiet output, minimum dynamic V _{OH}		2.9		V
V _{IH(D)}	High-level dynamic input voltage	2.31			V
V _{IL(D)}	Low-level dynamic input voltage			0.99	V

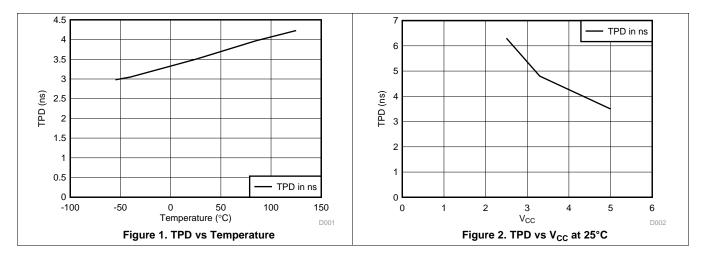
(1) Characteristics are for surface-mount packages only.

7.10 Operating Characteristics

 $T_A = 25^{\circ}C$

	PARAMETER	TEST C	ONDITIONS	Vcc	TYP	UNIT	
	O tauta a abba d	0 50 55	f 10 MU	3.3 V	16.3	- F	
C _{pd}	C _{pd} Power dissipation capacitance	Outputs enabled	C _L = 50 pF,	f = 10 MHz	5 V	17.8	pF

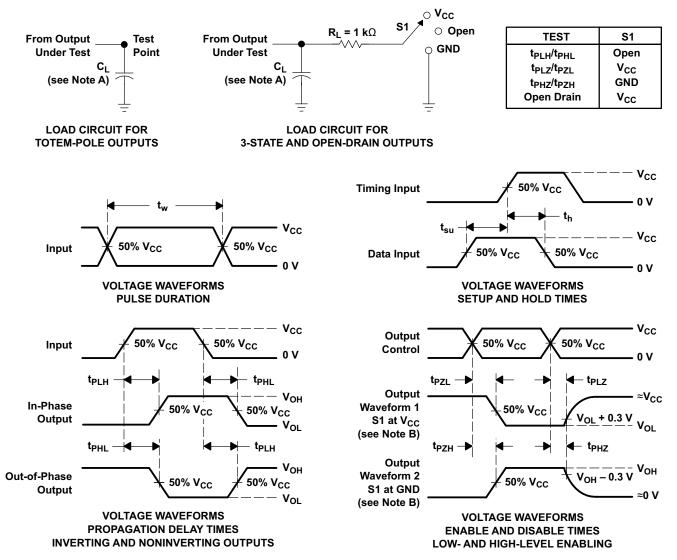
7.11 Typical Characteristics



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8 Parameter Measurement Information



NOTES: A. C_L includes probe and jig capacitance.

- B. Waveform 1 is for an output with internal conditions such that the output is low, except when disabled by the output control. Waveform 2 is for an output with internal conditions such that the output is high, except when disabled by the output control.
- C. All input pulses are supplied by generators having the following characteristics: PRR \leq 1 MHz, Z_O = 50 Ω , t_r \leq 3 ns, t_f \leq 3 ns.
- D. The outputs are measured one at a time, with one input transition per measurement.
- E. t_{PLZ} and t_{PHZ} are the same as t_{dis} .
- F. t_{PZL} and t_{PZH} are the same as t_{en} .
- G. t_{PHL} and t_{PLH} are the same as t_{pd} .
- H. All parameters and waveforms are not applicable to all devices.

Figure 3. Load Circuit and Voltage Waveforms



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9 Detailed Description

9.1 Overview

The SN74LV541A device is an octal buffers/driver designed for 2-V to 5.5-V V_{CC} operation.

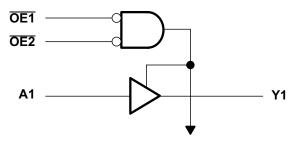
The SN74LV541A device is ideal for driving bus lines or buffer memory address registers. It features inputs and outputs on opposite sides of the package to facilitate printed circuit board layout.

The 3-state control gate is a two-input AND gate with active-low inputs so that if either output-enable ($\overline{OE1}$ or $\overline{OE2}$) input is high, all corresponding outputs are in the high-impedance state. The outputs provide non-inverted data when they are not in the high-impedance state.

To ensure the high-impedance state during power up or power down, both \overline{OE} should be tied to V_{CC} through a pull-up resistor; the minimum value of the resistor is determined by the current-sinking capability of the driver.

The SN74LV541A device are fully specified for partial-power-down applications using I_{off}. The I_{off} circuitry disables the outputs, preventing damaging current backflow through the devices when they are powered down.

9.2 Functional Block Diagram



To Seven Other Channels Figure 4. Logic Diagram (Positive Logic)

9.3 Feature Description

- · Wide operating voltage range
 - Operates from 2 V to 5.5 V
- Allows down-voltage translation
- Inputs accept voltages to 5.5 V
- I_{off} feature
 - Allows voltages on the inputs when V_{CC} is 0 V

9.4 Device Functional Modes

Table 2. Function Table(Each Buffer or Driver)

	INPUT	OUTPUT	
OE1	OE2	Α	Y
L	L	L	L
L	L	Н	Н
Н	Х	Х	Z
Х	Н	Х	Z

SN74LV541A

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10 Application and Implementation

NOTE

Information in the following applications sections is not part of the TI component specification, and TI does not warrant its accuracy or completeness. TI's customers are responsible for determining suitability of components for their purposes. Customers should validate and test their design implementation to confirm system functionality.

10.1 Application Information

SN74LV541A is a low-drive CMOS device that can be used for a multitude of bus interface type applications where the data needs to be retained or latched. It can produce 16 mA of drive current at 5 V, making it Ideal for driving multiple outputs and good for low noise applications. The inputs are 5.5-V tolerant allowing it to translate down to V_{CC} .

10.2 Typical Application

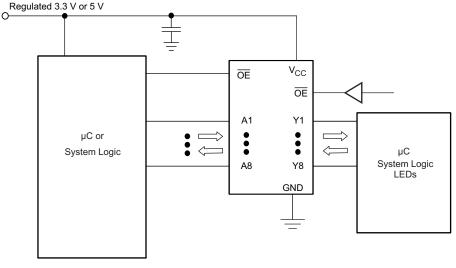


Figure 5. Typical Application Schematic

10.2.1 Design Requirements

This device uses CMOS technology and has balanced output drive. Care should be taken to avoid bus contention because it can drive currents that would exceed maximum limits. The high drive will also create fast edges into light loads, so routing and load conditions should be considered to prevent ringing.

10.2.2 Detailed Design Procedure

1. Recommended Input Conditions

- For rise time and fall time specifications, see $\Delta t/\Delta V$ in the *Recommended Operating Conditions* table.
- For specified High and low levels, see V_{IH} and V_{IL} in the *Recommended Operating Conditions* table.

Product Folder Links: SN74LV541A

- Inputs are overvoltage tolerant allowing them to go as high as 5.5 V at any valid V_{CC} .
- 2. Recommend Output Conditions
 - Load currents should not exceed 35 mA per output and 70 mA total for the part.
 - Outputs should not be pulled above V_{CC}.

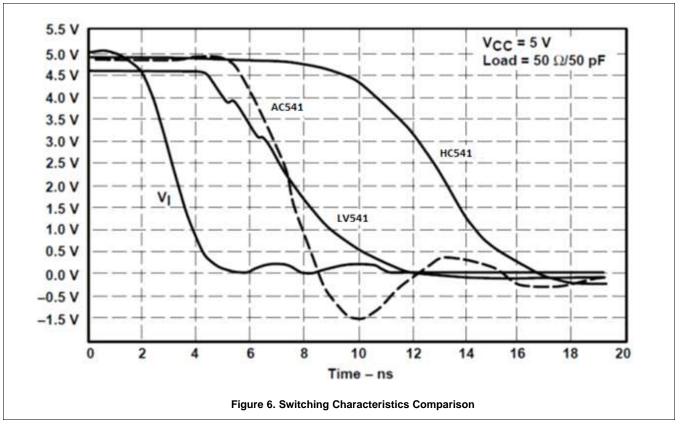
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Typical Application (continued)

10.2.3 Application Curves



11 Power Supply Recommendations

The power supply can be any voltage between the MIN and MAX supply voltage rating located in the *Recommended Operating Conditions* table.

Each V_{CC} pin should have a good bypass capacitor to prevent power disturbance. For devices with a single supply, 0.1 μ F is recommended. If there are multiple V_{CC} pins, 0.01 μ F or 0.022 μ F is recommended for each power pin. It is acceptable to parallel multiple bypass caps to reject different frequencies of noise. A 0.1 μ F and 1 μ F are commonly used in parallel. The bypass capacitor should be installed as close to the power pin as possible for best results.

TEXAS INSTRUMENTS

12 Layout

12.1 Layout Guidelines

When using multiple bit logic devices, inputs should not float. In many cases, functions or parts of functions of digital logic devices are unused. Some examples are when only two inputs of a triple-input AND gate are used, or when only 3 of the 4-buffer gates are used. Such input pins should not be left unconnected because the undefined voltages at the outside connections result in undefined operational states.

Specified in Figure 7 are rules that must be observed under all circumstances. All unused inputs of digital logic devices must be connected to a high or low bias to prevent them from floating. The logic level that should be applied to any particular unused input depends on the function of the device. Generally they will be tied to GND or V_{CC} , whichever makes more sense or is more convenient. It is acceptable to float outputs unless the part is a transceiver. If the transceiver has an output enable pin, it will disable the outputs section of the part when asserted. This will not disable the input section of the I/Os so they also cannot float when disabled.

12.2 Layout Example

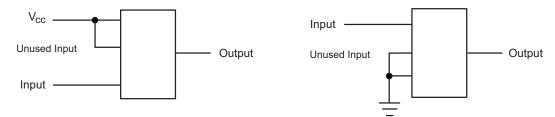


Figure 7. Layout Diagram

13 Device and Documentation Support

13.1 Related Links

The table below lists quick access links. Categories include technical documents, support and community resources, tools and software, and quick access to sample or buy.

Table 3. Related Links

PARTS	PRODUCT FOLDER	SAMPLE & BUY	TECHNICAL DOCUMENTS	TOOLS & SOFTWARE	SUPPORT & COMMUNITY
SN74LV541A	Click here	Click here	Click here	Click here	Click here

13.2 Trademarks

All trademarks are the property of their respective owners.

13.3 Electrostatic Discharge Caution



These devices have limited built-in ESD protection. The leads should be shorted together or the device placed in conductive foam during storage or handling to prevent electrostatic damage to the MOS gates.

13.4 Glossary

SLYZ022 — TI Glossary.

This glossary lists and explains terms, acronyms, and definitions.

14 Mechanical, Packaging, and Orderable Information

The following pages include mechanical, packaging, and orderable information. This information is the most current data available for the designated devices. This data is subject to change without notice and revision of this document. For browser-based versions of this data sheet, refer to the left-hand navigation.



24-Aug-2018

PACKAGING INFORMATION

Orderable Device	Status	Package Type	Package Drawing	Pins	Package Qty	Eco Plan (2)	Lead/Ball Finish	MSL Peak Temp	Op Temp (°C)	Device Marking (4/5)	Samples
SN74LV541ADBR	ACTIVE	SSOP	DB	20	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 125	LV541A	Samples
SN74LV541ADBRE4	ACTIVE	SSOP	DB	20	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 125	LV541A	Samples
SN74LV541ADBRG4	ACTIVE	SSOP	DB	20	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 125	LV541A	Samples
SN74LV541ADW	ACTIVE	SOIC	DW	20	25	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 125	LV541A	Samples
SN74LV541ADWR	ACTIVE	SOIC	DW	20	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 125	LV541A	Samples
SN74LV541ANSR	ACTIVE	SO	NS	20	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 125	74LV541A	Samples
SN74LV541APW	ACTIVE	TSSOP	PW	20	70	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 125	LV541A	Samples
SN74LV541APWG4	ACTIVE	TSSOP	PW	20	70	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 125	LV541A	Samples
SN74LV541APWR	ACTIVE	TSSOP	PW	20	2000	Green (RoHS & no Sb/Br)	CU NIPDAU CU SN	Level-1-260C-UNLIM	-40 to 125	LV541A	Samples
SN74LV541APWRG4	ACTIVE	TSSOP	PW	20	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 125	LV541A	Samples
SN74LV541APWT	ACTIVE	TSSOP	PW	20	250	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 125	LV541A	Samples
SN74LV541ARGYR	ACTIVE	VQFN	RGY	20	3000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-2-260C-1 YEAR	-40 to 125	LV541A	Samples

⁽¹⁾ The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

OBSOLETE: TI has discontinued the production of the device.

⁽²⁾ RoHS: TI defines "RoHS" to mean semiconductor products that are compliant with the current EU RoHS requirements for all 10 RoHS substances, including the requirement that RoHS substance do not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, "RoHS" products are suitable for use in specified lead-free processes. TI may reference these types of products as "Pb-Free".

RoHS Exempt: TI defines "RoHS Exempt" to mean products that contain lead but are compliant with EU RoHS pursuant to a specific EU RoHS exemption.



PACKAGE OPTION ADDENDUM

24-Aug-2018

Green: TI defines "Green" to mean the content of Chlorine (CI) and Bromine (Br) based flame retardants meet JS709B low halogen requirements of <=1000ppm threshold. Antimony trioxide based flame retardants must also meet the <=1000ppm threshold requirement.

⁽³⁾ MSL, Peak Temp. - The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

⁽⁴⁾ There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device.

⁽⁵⁾ Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device.

(6) Lead/Ball Finish - Orderable Devices may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead/Ball Finish values may wrap to two lines if the finish value exceeds the maximum column width.

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PACKAGE MATERIALS INFORMATION

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Texas Instruments

TAPE AND REEL INFORMATION





QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE



*All dimensions are nominal												
Device	Package Type	Package Drawing		SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
SN74LV541ADBR	SSOP	DB	20	2000	330.0	16.4	8.2	7.5	2.5	12.0	16.0	Q1
SN74LV541ADWR	SOIC	DW	20	2000	330.0	24.4	10.8	13.3	2.7	12.0	24.0	Q1
SN74LV541ANSR	SO	NS	20	2000	330.0	24.4	8.4	13.0	2.5	12.0	24.0	Q1
SN74LV541APWR	TSSOP	PW	20	2000	330.0	16.4	6.95	7.1	1.6	8.0	16.0	Q1
SN74LV541APWT	TSSOP	PW	20	250	330.0	16.4	6.95	7.1	1.6	8.0	16.0	Q1
SN74LV541ARGYR	VQFN	RGY	20	3000	330.0	12.4	3.8	4.8	1.6	8.0	12.0	Q1

TEXAS INSTRUMENTS

www.ti.com

PACKAGE MATERIALS INFORMATION

12-Jul-2018



*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
SN74LV541ADBR	SSOP	DB	20	2000	367.0	367.0	38.0
SN74LV541ADWR	SOIC	DW	20	2000	367.0	367.0	45.0
SN74LV541ANSR	SO	NS	20	2000	367.0	367.0	45.0
SN74LV541APWR	TSSOP	PW	20	2000	364.0	364.0	27.0
SN74LV541APWT	TSSOP	PW	20	250	367.0	367.0	38.0
SN74LV541ARGYR	VQFN	RGY	20	3000	367.0	367.0	35.0

MECHANICAL DATA



- D. The package thermal pad must be soldered to the board for thermal and mechanical performance.
- E. See the additional figure in the Product Data Sheet for details regarding the exposed thermal pad features and dimensions.
- The Pin 1 identifiers are either a molded, marked, or metal feature.
- G. Package complies to JEDEC MO-241 variation BA.



RGY (R-PVQFN-N20)

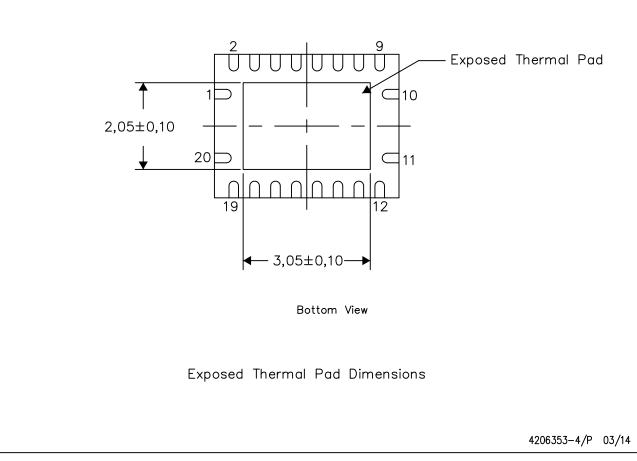
PLASTIC QUAD FLATPACK NO-LEAD

THERMAL INFORMATION

This package incorporates an exposed thermal pad that is designed to be attached directly to an external heatsink. The thermal pad must be soldered directly to the printed circuit board (PCB). After soldering, the PCB can be used as a heatsink. In addition, through the use of thermal vias, the thermal pad can be attached directly to the appropriate copper plane shown in the electrical schematic for the device, or alternatively, can be attached to a special heatsink structure designed into the PCB. This design optimizes the heat transfer from the integrated circuit (IC).

For information on the Quad Flatpack No-Lead (QFN) package and its advantages, refer to Application Report, QFN/SON PCB Attachment, Texas Instruments Literature No. SLUA271. This document is available at www.ti.com.

The exposed thermal pad dimensions for this package are shown in the following illustration.



NOTE: All linear dimensions are in millimeters





NOTES: A. All linear dimensions are in millimeters.

- B. This drawing is subject to change without notice.
- C. Publication IPC-7351 is recommended for alternate designs.
- D. This package is designed to be soldered to a thermal pad on the board. Refer to Application Note, Quad Flat-Pack QFN/SON PCB Attachment, Texas Instruments Literature No. SLUA271, and also the Product Data Sheets for specific thermal information, via requirements, and recommended board layout. These documents are available at www.ti.com http://www.ti.com.
- E. Laser cutting apertures with trapezoidal walls and also rounding corners will offer better paste release. Customers should contact their board assembly site for stencil design recommendations. Refer to IPC 7525 for stencil design considerations.
- F. Customers should contact their board fabrication site for minimum solder mask web tolerances between signal pads.



MECHANICAL DATA

PLASTIC SMALL-OUTLINE PACKAGE

0,51 0,35 ⊕0,25⊛ 1,27 8 14 0,15 NOM 5,60 8,20 5,00 7,40 \bigcirc Gage Plane ₽ 0,25 7 1 1,05 0,55 0°-10° Δ 0,15 0,05 Seating Plane — 2,00 MAX 0,10PINS ** 14 16 20 24 DIM 10,50 10,50 12,90 15,30 A MAX A MIN 9,90 9,90 12,30 14,70 4040062/C 03/03

NOTES: A. All linear dimensions are in millimeters.

NS (R-PDSO-G**)

14-PINS SHOWN

- B. This drawing is subject to change without notice.
- C. Body dimensions do not include mold flash or protrusion, not to exceed 0,15.



PW (R-PDSO-G20)

PLASTIC SMALL OUTLINE



NOTES:

A. All linear dimensions are in millimeters. Dimensioning and tolerancing per ASME Y14.5M-1994. β . This drawing is subject to change without notice.

Body length does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0,15 each side.

Body width does not include interlead flash. Interlead flash shall not exceed 0,25 each side.

E. Falls within JEDEC MO-153



LAND PATTERN DATA



NOTES: Α. All linear dimensions are in millimeters.

- B. This drawing is subject to change without notice.
 C. Publication IPC-7351 is recommended for alternate design.
- D. Laser cutting apertures with trapezoidal walls and also rounding corners will offer better paste release. Customers should contact their board assembly site for stencil design recommendations. Refer to IPC-7525 for other stencil recommendations.
- E. Customers should contact their board fabrication site for solder mask tolerances between and around signal pads.



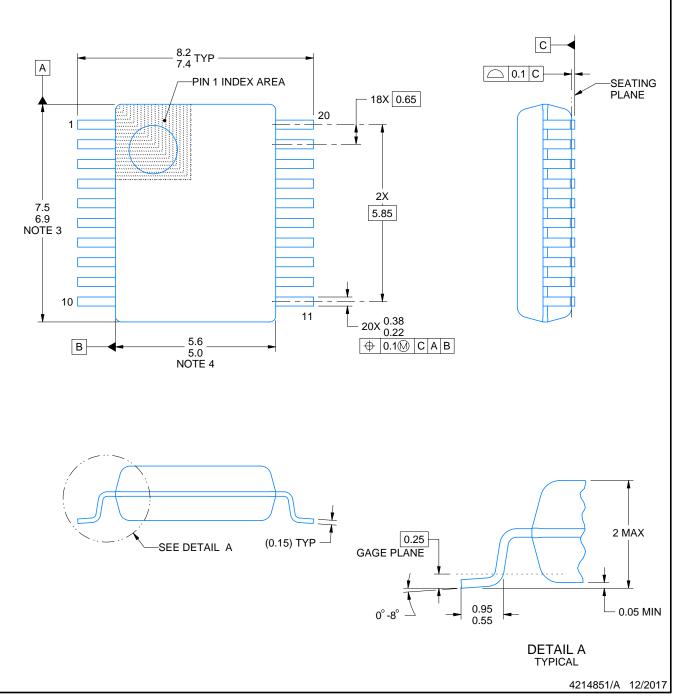
DB0020A



PACKAGE OUTLINE

TSSOP - 2 mm max height

SMALL OUTLINE PACKAGE



NOTES:

- 1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M. 2. This drawing is subject to change without notice. 3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not
- exceed 0.15 mm per side.
- 4. This dimension does not include interlead flash. Interlead flash shall not exceed 0.25 mm per side.
- 5. Reference JEDEC registration MO-150.

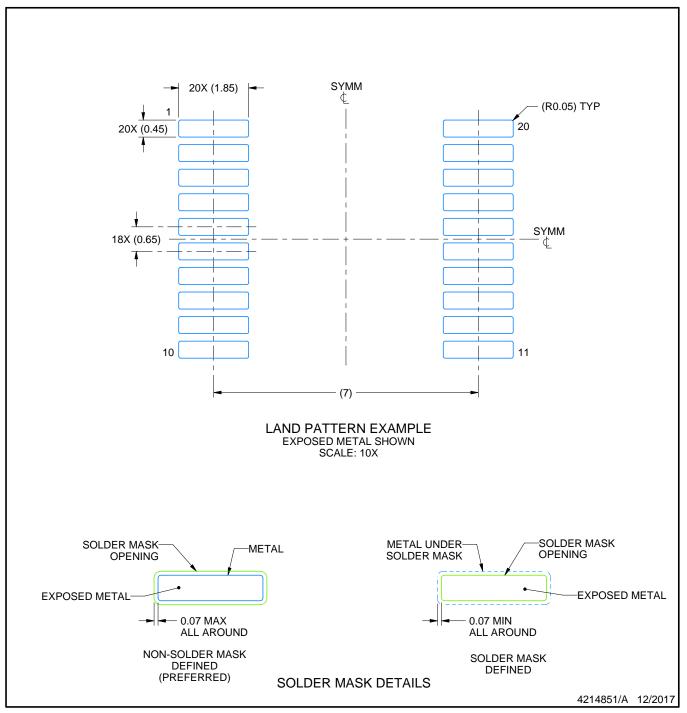


DB0020A

EXAMPLE BOARD LAYOUT

TSSOP - 2 mm max height

SMALL OUTLINE PACKAGE



NOTES: (continued)

6. Publication IPC-7351 may have alternate designs.

7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.

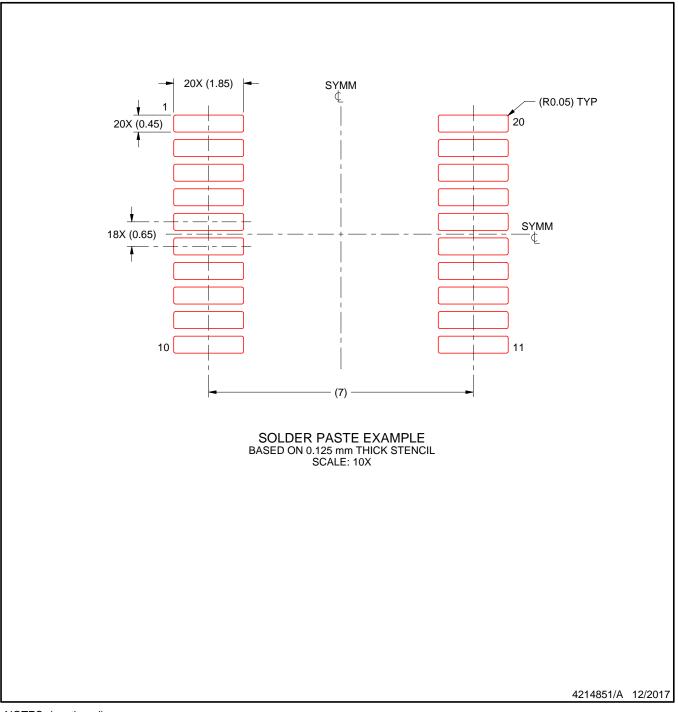


DB0020A

EXAMPLE STENCIL DESIGN

TSSOP - 2 mm max height

SMALL OUTLINE PACKAGE



NOTES: (continued)

- 8. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
- 9. Board assembly site may have different recommendations for stencil design.



DW0020A



PACKAGE OUTLINE

SOIC - 2.65 mm max height

SOIC



NOTES:

- 1. All linear dimensions are in millimeters. Dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M. 2. This drawing is subject to change without notice. 3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not
- exceed 0.15 mm per side.
- 4. This dimension does not include interlead flash. Interlead flash shall not exceed 0.43 mm per side.
- 5. Reference JEDEC registration MS-013.



DW0020A

EXAMPLE BOARD LAYOUT

SOIC - 2.65 mm max height

SOIC



NOTES: (continued)

6. Publication IPC-7351 may have alternate designs.

7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.



DW0020A

EXAMPLE STENCIL DESIGN

SOIC - 2.65 mm max height

SOIC



NOTES: (continued)

- 8. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
- 9. Board assembly site may have different recommendations for stencil design.



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